List of Publications by Year in descending order

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		136950	168389
111	3,470	32	53
papers	citations	h-index	g-index
110	110	110	2004
112	112	112	2984
all docs	docs citations	times ranked	citing authors

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#	Article	IF	CITATIONS
1	2D MoS ₂ Neuromorphic Devices for Brain‣ike Computational Systems. Small, 2017, 13, 1700933.	10.0	268
2	2D electric-double-layer phototransistor for photoelectronic and spatiotemporal hybrid neuromorphic integration. Nanoscale, 2019, 11, 1360-1369.	5.6	195
3	A Subâ€10 nm Vertical Organic/Inorganic Hybrid Transistor for Painâ€Perceptual and Sensitizationâ€Regulated Nociceptor Emulation. Advanced Materials, 2020, 32, e1906171.	21.0	135
4	Coplanar Multigate MoS ₂ Electric-Double-Layer Transistors for Neuromorphic Visual Recognition. ACS Applied Materials & Interfaces, 2018, 10, 25943-25948.	8.0	99
5	Ultralow-voltage transparent electric-double-layer thin-film transistors processed at room-temperature. Applied Physics Letters, 2009, 95, .	3.3	95
6	Photoelectric Visual Adaptation Based on 0Dâ€CsPbBr ₃ â€Quantumâ€Dots/2Dâ€MoS ₂ Mixedâ€Dimensional Heterojunction Transistor. Advanced Functional Materials, 2021, 31, 2010655.	14.9	93
7	Transient security transistors self-supported on biodegradable natural-polymer membranes for brain-inspired neuromorphic applications. Nanoscale, 2018, 10, 14893-14901.	5.6	90
8	Vertical 0Dâ€Perovskite/2Dâ€MoS ₂ van der Waals Heterojunction Phototransistor for Emulating Photoelectricâ€Synergistically Classical Pavlovian Conditioning and Neural Coding Dynamics. Small, 2020, 16, e2005217.	10.0	87
9	Flexible Vertical Photogating Transistor Network with an Ultrashort Channel for Inâ€Sensor Visual Nociceptor. Advanced Functional Materials, 2021, 31, 2104327.	14.9	85
10	PbS Nanoparticles for Ultrashort Pulse Generation in Optical Communication Region. Particle and Particle Systems Characterization, 2018, 35, 1800341.	2.3	82
11	Proton–electron-coupled MoS ₂ synaptic transistors with a natural renewable biopolymer neurotransmitter for brain-inspired neuromorphic learning. Journal of Materials Chemistry C, 2019, 7, 682-691.	5.5	69
12	Bidirectionally-trigged 2D MoS2 synapse through coplanar-gate electric-double-layer polymer coupling for neuromorphic complementary spatiotemporal learning. Organic Electronics, 2018, 63, 120-128.	2.6	65
13	Ion Migration Accelerated Reaction between Oxygen and Metal Halide Perovskites in Light and Its Suppression by Cesium Incorporation. Advanced Energy Materials, 2021, 11, 2002552.	19.5	64
14	Thermal oxidation of Ni films for p-type thin-film transistors. Physical Chemistry Chemical Physics, 2013, 15, 6875.	2.8	59
15	Femtosecond Laser Thermal Accumulation-Triggered Micro-/Nanostructures with Patternable and Controllable Wettability Towards Liquid Manipulating. Nano-Micro Letters, 2022, 14, 97.	27.0	58
16	Emerging uniform Cu ₂ O nanocubes for 251st harmonic ultrashort pulse generation. Journal of Materials Chemistry C, 2020, 8, 14386-14392.	5.5	57
17	Microporous SiO2 with huge electric-double-layer capacitance for low-voltage indium tin oxide thin-film transistors. Applied Physics Letters, 2009, 95, .	3.3	55
18	One-Shadow-Mask Self-Assembled Ultralow-Voltage Coplanar Homojunction Thin-Film Transistors. IEEE Electron Device Letters, 2010, 31, 1137-1139.	3.9	55

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19	Indium-tin-oxide thin film transistor biosensors for label-free detection of avian influenza virus H5N1. Analytica Chimica Acta, 2013, 773, 83-88.	5.4	55
20	Low-voltage electric-double-layer paper transistors gated by microporous SiO2 processed at room temperature. Applied Physics Letters, 2009, 95, 222108.	3.3	52
21	Low-voltage transparent electric-double-layer ZnO-based thin-film transistors for portable transparent electronics. Applied Physics Letters, 2010, 96, .	3.3	52
22	Research progress on hybrid organic–inorganic perovskites for photo-applications. Chinese Chemical Letters, 2020, 31, 3055-3064.	9.0	52
23	A biopolymer-gated ionotronic junctionless oxide transistor array for spatiotemporal pain-perception emulation in nociceptor network. Nanoscale, 2022, 14, 2316-2326.	5.6	52
24	Hardware implementation of photoelectrically modulated dendritic arithmetic and spike-timing-dependent plasticity enabled by an ion-coupling gate-tunable vertical OD-perovskite/2D-MoS ₂ hybrid-dimensional van der Waals heterostructure. Nanoscale, 2020, 12, 21798-21811.	5.6	51
25	Flexible protonic/electronic coupled neuron transistors self-assembled on paper substrates for logic applications. Applied Physics Letters, 2013, 102, 093509.	3.3	45
26	Tailoring micro/nanostructured porous polytetrafluoroethylene surfaces for dual-reversible transition of wettability and transmittance. Chemical Engineering Journal, 2022, 434, 134756.	12.7	43
27	Solution-processed natural gelatin was used as a gate dielectric for the fabrication of oxide field-effect transistors. Organic Electronics, 2016, 38, 357-361.	2.6	42
28	A homogeneous p–n junction diode by selective doping of few layer MoSe ₂ using ultraviolet ozone for high-performance photovoltaic devices. Nanoscale, 2019, 11, 13469-13476.	5.6	41
29	Lightweight flexible indium-free oxide TFTs with AND logic function employing chitosan biopolymer as self-supporting layer. Solid-State Electronics, 2019, 153, 16-22.	1.4	40
30	Polarization-perceptual anisotropic two-dimensional ReS ₂ neuro-transistor with reconfigurable neuromorphic vision. Materials Horizons, 2022, 9, 1448-1459.	12.2	38
31	Chitosan-gated low-voltage transparent indium-free aluminum-doped zinc oxide thin-film transistors. Organic Electronics, 2016, 33, 311-315.	2.6	37
32	The correlations of the electronic structure and film growth of 2,7-diocty[1]benzothieno[3,2-b]benzothiophene (C8-BTBT) on SiO ₂ . Physical Chemistry Chemical Physics, 2017, 19, 1669-1676.	2.8	34
33	Low-voltage transparent SnO2 nanowire transistors gated by microporous SiO2 solid-electrolyte with improved polarization response. Journal of Materials Chemistry, 2010, 20, 8010.	6.7	31
34	Junctionless Flexible Oxide-Based Thin-Film Transistors on Paper Substrates. IEEE Electron Device Letters, 2012, 33, 65-67.	3.9	31
35	Vertical organic-inorganic hybrid transparent oxide TFTs gated by biodegradable electric-double-layer biopolymer. Organic Electronics, 2017, 44, 1-5.	2.6	31
36	Low-Voltage Organic/Inorganic Hybrid Transparent Thin-Film Transistors Gated by Chitosan-Based Proton Conductors. IEEE Electron Device Letters, 2011, 32, 1549-1551.	3.9	30

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37	Interfacial electronic structures of MoOx/mixed perovskite photodetector. Organic Electronics, 2019, 65, 162-169.	2.6	30
38	Polymer-Decorated 2D MoS ₂ Synaptic Transistors for Biological Bipolar Metaplasticities Emulation*. Chinese Physics Letters, 2020, 37, 088501.	3.3	30
39	Poly(vinyl alcohol)-gated junctionless Al-Zn-O phototransistor for photonic and electric hybrid neuromorphic computation. Solid-State Electronics, 2020, 165, 107767.	1.4	30
40	In-plane-gate indium-tin-oxide thin-film transistors self-assembled on paper substrates. Applied Physics Letters, 2011, 98, .	3.3	29
41	Flexible Dual-Gate Oxide TFTs Gated by Chitosan Film on Paper Substrates. IEEE Electron Device Letters, 2013, 34, 259-261.	3.9	29
42	Low-voltage electric-double-layer MoS2 transistor gated via water solution. Solid-State Electronics, 2018, 150, 8-15.	1.4	29
43	Tuning the hysteresis voltage in 2D multilayer MoS2 FETs. Physica B: Condensed Matter, 2016, 498, 76-81.	2.7	27
44	Enhanced performance of multilayer MoS2 transistor employing a polymer capping layer. Organic Electronics, 2017, 40, 75-78.	2.6	27
45	Solution-processed ultra-flexible C8-BTBT organic thin-film transistors with the corrected mobility over 18Åcm2/(V s). Science Bulletin, 2020, 65, 791-795.	9.0	27
46	Recent progress on two-dimensional neuromorphic devices and artificial neural network. Current Applied Physics, 2021, 31, 182-198.	2.4	26
47	PbI ₂ –MoS ₂ Heterojunction: van der Waals Epitaxial Growth and Energy Band Alignment. Journal of Physical Chemistry Letters, 2019, 10, 4203-4208.	4.6	25
48	<i>In situ</i> surface modification of TiO2 by CaTiO3 to improve the UV stability and power conversion efficiency of perovskite solar cells. Applied Physics Letters, 2019, 115, .	3.3	25
49	Junctionless in-plane-gate transparent thin-film transistors. Applied Physics Letters, 2011, 99, .	3.3	24
50	From MoO ₂ @MoS ₂ Core–Shell Nanorods to MoS ₂ Nanobelts. Physica Status Solidi (B): Basic Research, 2018, 255, 1800254.	1.5	23
51	One-Volt Oxide Thin-Film Transistors on Paper Substrates Gated by \$hbox{SiO}_{2}-Based Solid Electrolyte With Controllable Operation Modes. IEEE Transactions on Electron Devices, 2010, 57, 2258-2263.	3.0	22
52	Transparent Junctionless Electric-Double-Layer Transistors Gated by a Reinforced Chitosan-Based Biopolymer Electrolyte. IEEE Transactions on Electron Devices, 2013, 60, 1951-1957.	3.0	22
53	Chitosan solid electrolyte as electric double layer in multilayer MoS ₂ transistor for lowâ€voltage operation. Physica Status Solidi (A) Applications and Materials Science, 2015, 212, 2219-2225.	1.8	22
54	Observation of abnormal mobility enhancement in multilayer MoS2 transistor by synergy of ultraviolet illumination and ozone plasma treatment. Physica E: Low-Dimensional Systems and Nanostructures, 2017, 87, 150-154.	2.7	21

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55	Famatinite Cu ₃ SbS ₄ nanocrystals as hole transporting material for efficient perovskite solar cells. Journal of Materials Chemistry C, 2018, 6, 7989-7993.	5.5	20
56	Type-II Interface Band Alignment in the vdW PbI ₂ –MoSe ₂ Heterostructure. ACS Applied Materials & Interfaces, 2020, 12, 32099-32105.	8.0	20
57	Graphene-based low-threshold and tunable optical bistability in one-dimensional photonic crystal Fano resonance heterostructure at optical communication band. Optics Express, 2020, 28, 34948.	3.4	20
58	Self-Assembled Ultralow-Voltage Flexible Transparent Thin-Film Transistors Gated by \$hbox{SiO}_{2}\$-Based Solid Electrolyte. IEEE Transactions on Electron Devices, 2011, 58, 547-552.	3.0	19
59	High-Sensitivity Terahertz Refractive Index Sensor in a Multilayered Structure with Graphene. Nanomaterials, 2020, 10, 500.	4.1	19
60	Flexible Low-Voltage Electric-Double-Layer TFTs Self-Assembled on Paper Substrates. IEEE Electron Device Letters, 2011, 32, 518-520.	3.9	18
61	Initial photochemical stability in perovskite solar cells based on the Cu electrode and the appropriate charge transport layers. Synthetic Metals, 2018, 246, 101-107.	3.9	18
62	Fe ₃ O ₄ nanoparticles as a saturable absorber for giant chirped pulse generation. Beilstein Journal of Nanotechnology, 2019, 10, 1065-1072.	2.8	18
63	Self-Assembled In-Plane Gate Oxide-Based Homojunction Thin-Film Transistors. IEEE Electron Device Letters, 2011, 32, 500-502.	3.9	17
64	Tuning the threshold voltage from depletion to enhancement mode in a multilayer MoS ₂ transistor via oxygen adsorption and desorption. Physical Chemistry Chemical Physics, 2016, 18, 685-689.	2.8	17
65	Dual in-plane-gate oxide-based thin-film transistors with tunable threshold voltage. Applied Physics Letters, 2011, 99, 113504.	3.3	16
66	Bio-inspired coplanar-gate-coupled ITO-free oxide-based transistors employing natural nontoxic bio-polymer electrolyte. Organic Electronics, 2016, 37, 474-478.	2.6	16
67	Low-power logic computing realized in a single electric-double-layer MoS 2 transistor gated with polymer electrolyte. Solid-State Electronics, 2018, 144, 1-6.	1.4	16
68	Vertical low-voltage oxide transistors gated by microporous SiO2/LiCl composite solid electrolyte with enhanced electric-double-layer capacitance. Applied Physics Letters, 2010, 97, 052104.	3.3	14
69	Fullerene (C60) interlayer modification on the electronic structure and the film growth of 2,7-diocty[1]benzothieno-[3,2-b]benzothiophene on SiO2. Synthetic Metals, 2017, 229, 1-6.	3.9	14
70	Energy Level Evolution and Oxygen Exposure of Fullerene/Black Phosphorus Interface. Journal of Physical Chemistry Letters, 2018, 9, 5254-5261.	4.6	13
71	Recent Progress in Anisotropic 2D Semiconductors: From Material Properties to Photoelectric Detection. Physica Status Solidi (A) Applications and Materials Science, 2021, 218, 2100204.	1.8	13
72	Low-Voltage Oxide-Based Electric-Double-Layer TFTs Gated by Stacked \$hbox{SiO}_{2}\$ Electrolyte/Chitosan Hybrid Dielectrics. IEEE Electron Device Letters, 2012, 33, 848-850.	3.9	12

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73	Recent Progress on Neuromorphic Synapse Electronics: From Emerging Materials, Devices, to Neural Networks. Journal of Nanoscience and Nanotechnology, 2018, 18, 8003-8015.	0.9	12
74	Interface Energy-Level Alignment between Black Phosphorus and F ₁₆ CuPc Molecular Films. Journal of Physical Chemistry C, 2019, 123, 10443-10450.	3.1	12
75	Low-Voltage Electric-Double-Layer TFTs on \$ hbox{SiO}_{2}\$-Covered Paper Substrates. IEEE Electron Device Letters, 2011, 32, 1543-1545.	3.9	10
76	Ultralow-Voltage Transparent \$hbox{In}_{2} hbox{O}_{3}\$ Nanowire Electric-Double-Layer Transistors. IEEE Electron Device Letters, 2011, 32, 315-317.	3.9	10
77	Dual-Gate MoS2FET With a Coplanar-Gate Engineering. IEEE Transactions on Electron Devices, 2016, 63, 573-577.	3.0	10
78	Lead sulfide nanoparticles for dual-wavelength ultrashort pulse generation. Nanotechnology, 2020, 31, 085202.	2.6	10
79	Effective passivation of black phosphorus against atmosphere by quasi-monolayer of F4TCNQ molecules. Applied Physics Letters, 2020, 117, .	3.3	10
80	Low-Voltage Transparent Indium–Zinc–Oxide Coplanar Homojunction TFTs Self-Assembled on Inorganic Proton Conductors. IEEE Transactions on Electron Devices, 2011, 58, 764-768.	3.0	9
81	Photoemission studies of C8-BTBT/La0.67Sr0.33MnO3 interface. Synthetic Metals, 2020, 260, 116261.	3.9	9
82	Modeling of low-voltage oxide-based electric-double-layer thin-film transistors fabricated at room temperature. Applied Physics Letters, 2011, 98, .	3.3	8
83	Low threshold optical bistability in graphene/waveguide hybrid structure at terahertz frequencies. Optics Communications, 2021, 499, 127282.	2.1	8
84	From Pain to Fear Recognition via Pavlovian Learning in an Organic–Inorganic Hybrid Neuromorphic Transistor. Advanced Electronic Materials, 2022, 8, .	5.1	8
85	Electrostatic modification of oxide semiconductors by electric double layers of microporous SiO2-based solid electrolyte. Journal of Applied Physics, 2011, 109, .	2.5	7
86	Interface Electronic Structure between Au and Black Phosphorus. Journal of Physical Chemistry C, 2018, 122, 18405-18411.	3.1	7
87	Software cost estimation through conceptual requirement. , 2003, , .		6
88	Anomalous Threshold Voltage Shift and Surface Passivation of Transparent Indium–Zinc–Oxide Electric-Double-Layer TFTs. IEEE Electron Device Letters, 2011, 32, 910-912.	3.9	6
89	The effect of air exposure on device performance of flexible C8-BTBT organic thin-film transistors with hygroscopic insulators. Science China Materials, 2020, 63, 2551-2559.	6.3	6
90	Enhanced and tunable terahertz spin hall effect of reflected light due to tamm plasmons with topological insulators. Results in Physics, 2020, 19, 103392.	4.1	6

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91	High-sensitivity detection of Concanavalin A using MoS ₂ -based field effect transistor biosensor. Journal Physics D: Applied Physics, 2021, 54, 245401.	2.8	6
92	Anisotropic 2D materials for post-Moore photoelectric devices. Journal of Semiconductors, 2022, 43, 010201.	3.7	6
93	Water-induced dual ultrahigh mobilities over 400 cm ² V ^{â^`1} s ^{â^`1} in 2D MoS ₂ transistors for ultralow-voltage operation and photoelectric synapse perception. Journal of Materials Chemistry C, 2022, 10, 5249-5256.	5.5	6
94	MoS2-based multiterminal ionic transistor with orientation-dependent STDP learning rules. Solid-State Electronics, 2022, 194, 108386.	1.4	6
95	Automated elicitation of inclusion dependencies from the source code for database transactions. Journal of Software: Evolution and Process, 2003, 15, 379-392.	1.1	5
96	Low-Voltage Oxide Homojunction Electric-Double-Layer Transistors Gated by Ion-Incorporated Inorganic Solid Electrolytes. Japanese Journal of Applied Physics, 2010, 49, 110201.	1.5	5
97	Vertical Oxide Homojunction TFTs of 0.8 V Gated by \$ hbox{H}_{3}hbox{PO}_{4}\$-Treated \$hbox{SiO}_{2}\$ Nanogranular Dielectric. IEEE Electron Device Letters, 2010, , .	3.9	5
98	Modification of C60 nano-interlayers on organic field-effect transistors based on 2,7-diocty[1]benzothieno-[3,2-b]benzothiophene (C8-BTBT)/SiO2. Results in Physics, 2020, 19, 103590.	4.1	5
99	Fully Optical-Driving Ionotronic InGaZnO ₄ Phototransistor for Gate-Tunable Bidirectional Photofiltering and Visual Perception. IEEE Transactions on Electron Devices, 2022, 69, 4382-4385.	3.0	5
100	Low-Voltage Oxide-Based TFTs Self-Assembled on Paper Substrates With Tunable Threshold Voltage. IEEE Transactions on Electron Devices, 2012, 59, 380-384.	3.0	4
101	Modification of an ultrathin C ₆₀ interlayer on the electronic structure and molecular packing of C8-BTBT on HOPG. Physical Chemistry Chemical Physics, 2020, 22, 25264-25271.	2.8	4
102	Tuning the Threshold Voltage of Double-Gate Low-Voltage Transparent Oxide-Based TFTs by a Lateral In-Plane Gate. IEEE Electron Device Letters, 2011, 32, 1710-1712.	3.9	3
103	2D transition metal dichalcogenides for neuromorphic vision system. Journal of Semiconductors, 2021, 42, 090203.	3.7	3
104	Modification of FA0.85MA0.15Pb(I0.85Br0.15)3 Films by NH2-POSS. Crystals, 2021, 11, 1544.	2.2	3
105	Tunable optical bistability in graphene Tamm plasmon/Bragg reflector hybrid structure at terahertz frequencies. Results in Physics, 2022, 39, 105735.	4.1	3
106	Microporous SiO2-based solid electrolyte with improved polarization response for 0.8 V transparent thin-film transistors. Journal Physics D: Applied Physics, 2010, 43, 295103.	2.8	2
107	Density-of-State and Trap Modeling of Low-Voltage Electric-Double-Layer TFTs. IEEE Electron Device Letters, 2011, 32, 512-514.	3.9	2
108	Electronic Structures and Nanofilm Growth of 2,7-Dioctyl[1]Benzothieno[3,2-b]Benzothiophene on Black Phosphorus. Journal of Nanoscience and Nanotechnology, 2018, 18, 4332-4336.	0.9	2

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109	Neuromorphic Photoelectric Devices: Vertical 0Dâ€Perovskite/2Dâ€MoS ₂ van der Waals Heterojunction Phototransistor for Emulating Photoelectricâ€Synergistically Classical Pavlovian Conditioning and Neural Coding Dynamics (Small 45/2020). Small, 2020, 16, 2070244.	10.0	2
110	Low-voltage indium-zinc-oxide thin film transistors gated by solution-processed chitosan-based proton conductors. , 2011, , .		1
111	Tunable Superluminal and Subluminal Reflected Group Delay in an Air-Weyl Semimetal Film-Weyl Semimetal Substrate Layered System. IEEE Journal of Quantum Electronics, 2022, 58, 1-6.	1.9	1